Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass or ceramic Overall Length: 0.300 inches Terminal Length: 0.900 inches Overall Diameter:

0.180 inches

Mounting Method:

Terminal

Features Provided:

Burn in and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

600.0 reverse voltage, instantaneous

Current Rating Per Characteristic:

3.00 amperes forward current, average absolute and 700.00 microamperes forward current, average outside diameter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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